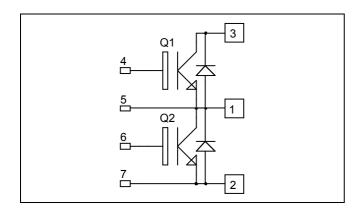


Phase leg Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 600V$$
  
 $I_{C} = 400A$  @  $T_{C} = 80^{\circ}C$ 



#### **Application**

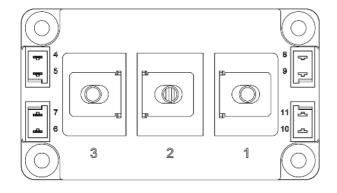
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
  - Kelvin emitter for easy drive
- High level of integration
- M6 power connectors



- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive  $T_C$  of  $V_{\text{CEsat}}$
- **RoHS Compliant**



#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		600	V
$I_{\mathrm{C}}$	Continuous Collector Current	$T_C = 25^{\circ}C$	500	
	Continuous Conector Current	$T_C = 80$ °C	400	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	800	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Maximum Power Dissipation	$T_C = 25$ °C	1250	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	800A @ 520V	

😘 🚓 UTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				500	μA
V <sub>CE(sat)</sub>	Collector Emitter saturation Voltage		$T_j = 25$ °C		1.5	1.9	V
				1.7		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 6.4$ mA		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		24		
$C_{oes}$	Output Capacitance	$V_{CE} = 25V$		1.5		nF
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz		0.75		
$Q_{G}$	Gate charge	V <sub>GE</sub> =±15V, I <sub>C</sub> =400A V <sub>CE</sub> =300V		4.2		μС
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C)		110		ns
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$		50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 300V$ $I_C = 400A$		490		
$T_{\mathrm{f}}$	Fall Time	$R_G = 1.5\Omega$		50		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C)		130		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$		60		ns
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 400A$		530		
$T_{\mathrm{f}}$	Fall Time	$R_G = 1.5\Omega$		70		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $T_{j} = 25^{\circ}C$		3.2		
Lon	Turn on Energy	$V_{Bus} = 300V$ $T_i = 150^{\circ}C$		3.4		mJ
$E_{off}$	Turn off Energy	$I_C = 400A \qquad T_j = 25^{\circ}C$		15		1110
2011	Tana on Energy	$R_G = 1.5\Omega$ $T_j = 150^{\circ}C$		15.5		
$I_{sc}$	Short Circuit data	$V_{GE} \le 15V ; V_{Bus} = 360V$ $t_p \le 6\mu s ; T_j = 150^{\circ}C$		2000		A

Reverse diode ratings and characteristics

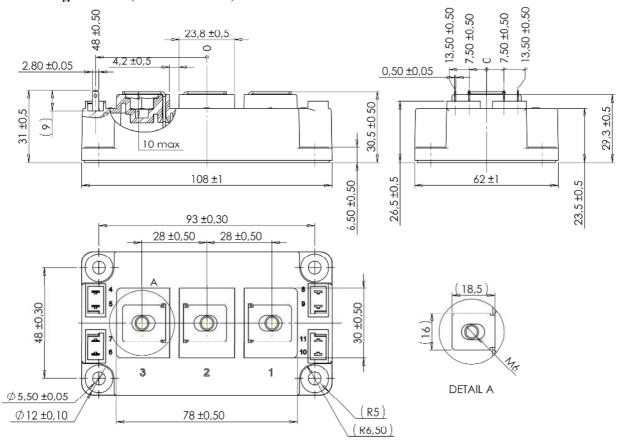
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			600			V
$I_{RRM}$	Maximum Reverse Leakage Current	$V_R=600V$	$T_i = 25$ °C $T_i = 150$ °C			500 750	μΑ
$I_{\mathrm{F}}$	DC Forward Current		$Tc = 80^{\circ}C$		400		A
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 400A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.6	2	V
v <sub>F</sub>			$T_{i} = 150^{\circ}C$		1.5		<b>'</b>
4	Reverse Recovery Time		$T_j = 25^{\circ}C$		125		
$t_{rr}$			$T_{j} = 150^{\circ}C$		180		ns
0	$I_F = 400A$	$T_j = 25^{\circ}C$		18.8		C	
$Q_{rr}$	Reverse Recovery Charge	$V_R = 300V$ di/dt = 4800A/us	$T_i = 150^{\circ}C$		39.5		μC
Г	E <sub>rr</sub> Reverse Recovery Energy	αι/αι 1000/1/μ3	$T_j = 25^{\circ}C$		4.4		Т
$\mathbf{E}_{\mathrm{rr}}$		$T_{\rm j} = 150^{\circ}{\rm C}$		9.6		mJ	



### Thermal and package characteristics

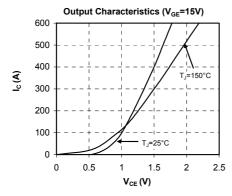
Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance		IGBT			0.12	°C/W
1\(\text{thJC}\)			Diode			0.20	C/ VV
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range	perating junction temperature range		-40		175	
$T_{STG}$	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		125	
Torque	Mounting torque	For terminals	M6	3		5	N.m
		To Heatsink	M6	3		5	18.111
Wt	Package Weight					350	g

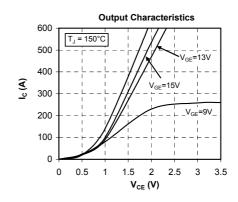
### D3 Package outline (dimensions in mm)

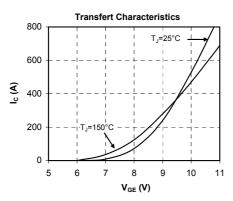


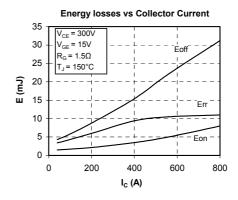


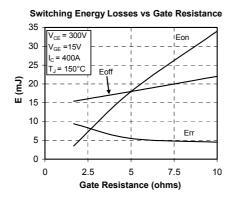
### **Typical Performance Curve**

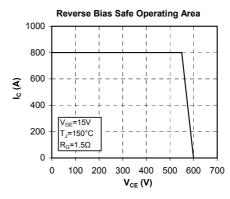


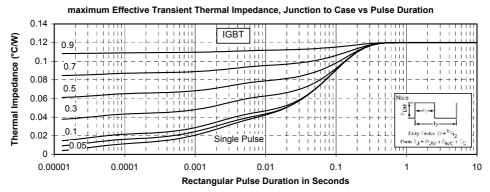




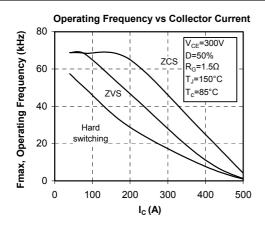


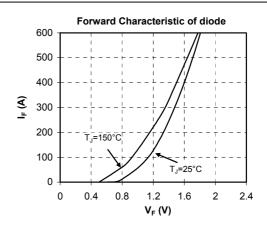


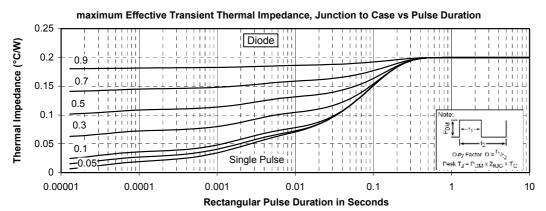














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